

BCR505E6778HTSA1

BCR505E6778HTSA1 Information

www.eelegoer.com	 BCR505E6778HTSA1 Infineon Technologies Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased TRANS PREBIAS NPN 250MW SOT23 TO-236-3, SC-59, SOT-23-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BCR505E6778HTSA1 Specifications

	Report errors?
Supplier Device Package	PG-SOT23-3
Package / Case	TO-236-3, SC-59, SOT-23-3
Mounting Type	Surface Mount
Power - Max	330mW
Frequency - Transition	100MHz
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	300mV @ 2.5mA, 50mA
DC Current Gain (hFE) (Min) @ Ic, Vce	70 @ 50mA, 5V
Resistor - Emitter Base (R2) (Ohms)	10k
Resistor - Base (R1) (Ohms)	2.2k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	500mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	TO-236-3, SC-59, SOT-23-3
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Infineon Technologies
Manufacturer Part Number	BCR505E6778HTSA1

BCR505E6778HTSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BCR505E6778HTSA1 Payment Methods



If you have any question about BCR505E6778HTSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com